

FS3UM-16A

HIGH-SPEED SWITCHING USE

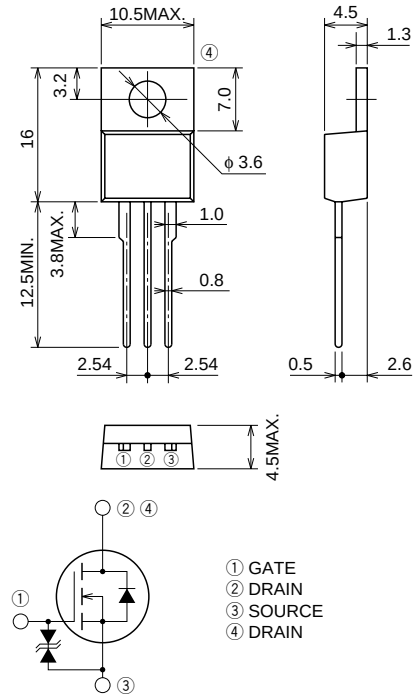
FS3UM-16A



- V_{DS} 800V
- $r_{DS(ON)}(MAX)$ 3.3Ω
- I_D 3A

OUTLINE DRAWING

Dimensions in mm



TO-220

APPLICATION

SMPS, DC-DC Converter, battery charger, power supply of printer, copier, HDD, FDD, TV, VCR, personal computer etc.

MAXIMUM RATINGS (Tc = 25°C)

Symbol	Parameter	Conditions	Ratings	Unit
V_{DS}	Drain-source voltage	$V_{GS} = 0V$	800	V
V_{GSS}	Gate-source voltage	$V_{DS} = 0V$	± 30	V
I_D	Drain current		3	A
I_{DM}	Drain current (Pulsed)		9	A
P_D	Maximum power dissipation		100	W
T_{ch}	Channel temperature		-55 ~ +150	°C
T_{stg}	Storage temperature		-55 ~ +150	°C
—	Weight	Typical value	2	g

ELECTRICAL CHARACTERISTICS (T_{ch} = 25°C)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V (BR) DSS	Drain-source breakdown voltage	I _D = 1mA, V _{GS} = 0V	800	—	—	V
V (BR) GSS	Gate-source breakdown voltage	I _{GS} = ±100μA, V _{DS} = 0V	±30	—	—	V
I _{GSS}	Gate-source leakage current	V _{GS} = ±25V, V _{DS} = 0V	—	—	±10	μA
I _{DSS}	Drain-source leakage current	V _{DS} = 800V, V _{GS} = 0V	—	—	1	mA
V _{GS} (th)	Gate-source threshold voltage	I _D = 1mA, V _{DS} = 10V	2	3	4	V
r _{DS} (ON)	Drain-source on-state resistance	I _D = 1.5A, V _{GS} = 10V	—	2.53	3.30	Ω
V _{DS} (ON)	Drain-source on-state voltage	I _D = 1.5A, V _{GS} = 10V	—	3.80	4.95	V
y _{fs}	Forward transfer admittance	I _D = 1.5A, V _{DS} = 10V	2.1	3.5	—	S
C _{iss}	Input capacitance	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz	—	770	—	pF
C _{oss}	Output capacitance		—	77	—	pF
C _{rss}	Reverse transfer capacitance		—	13	—	pF
t _d (on)	Turn-on delay time	V _{DD} = 200V, I _D = 1.5A, V _{GS} = 10V, R _{GEN} = R _{GS} = 50Ω	—	15	—	ns
t _r	Rise time		—	15	—	ns
t _d (off)	Turn-off delay time		—	90	—	ns
t _f	Fall time		—	25	—	ns
V _{SD}	Source-drain voltage	I _S = 1.5A, V _{GS} = 0V	—	1.0	1.5	V
R _{th} (ch-c)	Thermal resistance	Channel to case	—	—	1.25	°C/W

PERFORMANCE CURVES

